



**N-CHANNEL MOSFET**  
**Qualified per MIL-PRF-19500/592**

*Qualified Levels:*  
**JAN, JANTX, and JANTXV**

**DESCRIPTION**

This family of switching transistors is military qualified up to the JANTXV level for high-reliability applications. These devices are also available in a thru hole TO-254AA package. Microsemi also offers numerous other transistor products to meet higher and lower power ratings with various switching speed requirements in both through-hole and surface-mount packages.

**Important:** For the latest information, visit our website <http://www.microsemi.com>.

**FEATURES**

- Surface mount equivalent of JEDEC registered 2N7224, 2N7225, 2N7227 and 2N7228 number series.
- JAN, JANTX, and JANTXV qualifications are available per MIL-PRF-19500/592. (See [part nomenclature](#) for all available options.)
- RoHS compliant by design.

**APPLICATIONS / BENEFITS**

- Low-profile design.
- Military and other high-reliability applications.

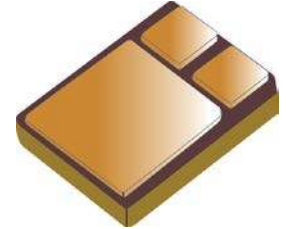
**MAXIMUM RATINGS @ T<sub>A</sub> = +25 °C unless otherwise stated**

| Parameters / Test Conditions                                | Symbol                            | Value       | Unit |
|---|-----------------------------------|-------------|------|
| Operating & Storage Junction Temperature Range              | T <sub>J</sub> & T <sub>stg</sub> | -55 to +150 | °C   |
| Thermal Resistance Junction-to-Case                         | R <sub>θJC</sub>                  | 0.83        | °C/W |
| Total Power Dissipation @ T <sub>A</sub> = +25 °C           | P <sub>T</sub>                    | 4           | W    |
| @ T <sub>C</sub> = +25 °C <sup>(1)</sup>                    |                                   | 150         |      |
| Gate-Source Voltage, dc                                     | V <sub>GS</sub>                   | ± 20        | V    |
| Drain Current, dc @ T <sub>C</sub> = +25 °C <sup>(2)</sup>  | I <sub>D1</sub>                   | 2N7224U     | 34.0 |
|   |                                   | 2N7225U     | 27.4 |
|   |                                   | 2N7227U     | 14.0 |
|   |                                   | 2N7228U     | 12.0 |
| Drain Current, dc @ T <sub>C</sub> = +100 °C <sup>(2)</sup> | I <sub>D2</sub>                   | 2N7224U     | 21   |
|   |                                   | 2N7225U     | 17   |
|   |                                   | 2N7227U     | 9    |
|   |                                   | 2N7228U     | 8    |
| Off-State Current (Peak Total Value) <sup>(3)</sup>         | I <sub>DM</sub>                   | 2N7224U     | 136  |
|   |                                   | 2N7225U     | 110  |
|   |                                   | 2N7227U     | 56   |
|   |                                   | 2N7228U     | 48   |
| Source Current  | I <sub>S</sub>                    | 2N7224U     | 34.0 |
|   |                                   | 2N7225U     | 27.4 |
|   |                                   | 2N7227U     | 14.0 |
|   |                                   | 2N7228U     | 12.0 |
|   |                                   |             | A    |

- NOTES:**
1. Derated linearly by 1.2 W/°C for T<sub>C</sub> > +25 °C.
  2. The following formula derives the maximum theoretical ID limit. ID is limited by package and internal wires and may also be limited by pin diameter:


$$I_D = \sqrt{\frac{T_J(\text{max}) - T_C}{R_{\theta JC} \times R_{DS(on)} @ T_J(\text{max})}}$$

3. I<sub>DM</sub> = 4 x I<sub>D1</sub> as calculated in note 2.



**U (SMD-1 or TO-267AB) Package**

Also available in:

**TO-254AA package**  
 (leaded)  
 [2N7224 & 2N7228](#)

**MSC – Lawrence**

6 Lake Street,  
 Lawrence, MA 01841  
 Tel: 1-800-446-1158 or  
 (978) 620-2600  
 Fax: (978) 689-0803

**MSC – Ireland**

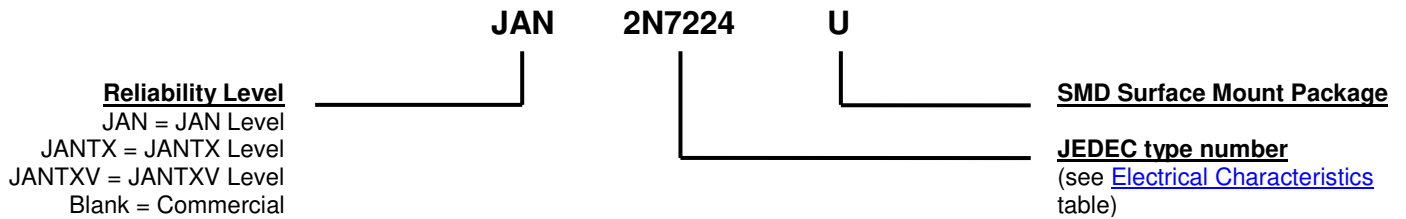
Gort Road Business Park,  
 Ennis, Co. Clare, Ireland  
 Tel: +353 (0) 65 6840044  
 Fax: +353 (0) 65 6822298

**Website:**

[www.microsemi.com](http://www.microsemi.com)

**MECHANICAL and PACKAGING**

- CASE: Ceramic and gold over nickel plated steel.
- TERMINALS: Gold over nickel plated tungsten/copper.
- MARKING: Part number, date code, A = anode.
- WEIGHT: 0.9 grams.
- See [Package Dimensions](#) on last page.

**PART NOMENCLATURE**

**SYMBOLS & DEFINITIONS**

| Symbol          | Definition   |
|-----------------|--|
| di/dt           | Rate of change of diode current while in reverse-recovery mode, recorded as maximum value. |
| I <sub>F</sub>  | Forward current  |
| R <sub>G</sub>  | Gate drive impedance   |
| V <sub>DD</sub> | Drain supply voltage   |
| V <sub>DS</sub> | Drain source voltage, dc   |
| V <sub>GS</sub> | Gate source voltage, dc  |

**ELECTRICAL CHARACTERISTICS @  $T_A = +25\text{ }^\circ\text{C}$ , unless otherwise noted**

| Parameters / Test Conditions   | Symbol  | Min.                     | Max.                             | Unit          |
|--|---|--------------------------|----------------------------------|---------------|
| <b>OFF CHARACTERISTICS</b>   |   |                          |                                  |               |
| Drain-Source Breakdown Voltage<br>$V_{GS} = 0\text{ V}$ , $I_D = 1.0\text{ mA}$  | 2N7224U<br>2N7225U<br>2N7227U<br>2N7228U<br>$V_{(BR)DSS}$ | 100<br>200<br>400<br>500 |                                  | V             |
| Gate-Source Voltage (Threshold)<br>$V_{DS} \geq V_{GS}$ , $I_D = 0.25\text{ mA}$<br>$V_{DS} \geq V_{GS}$ , $I_D = 0.25\text{ mA}$ , $T_J = +125\text{ }^\circ\text{C}$<br>$V_{DS} \geq V_{GS}$ , $I_D = 0.25\text{ mA}$ , $T_J = -55\text{ }^\circ\text{C}$  | $V_{GS(th)1}$<br>$V_{GS(th)2}$<br>$V_{GS(th)3}$           | 2.0<br>1.0               | 4.0<br>5.0                       | V             |
| Gate Current<br>$V_{GS} = \pm 20\text{ V}$ , $V_{DS} = 0\text{ V}$<br>$V_{GS} = \pm 20\text{ V}$ , $V_{DS} = 0\text{ V}$ , $T_J = +125\text{ }^\circ\text{C}$  | $I_{GSS1}$<br>$I_{GSS2}$                                  |                          | $\pm 100$<br>$\pm 200$           | nA            |
| Drain Current<br>$V_{GS} = 0\text{ V}$ , $V_{DS} = 80\text{ V}$<br>$V_{GS} = 0\text{ V}$ , $V_{DS} = 160\text{ V}$<br>$V_{GS} = 0\text{ V}$ , $V_{DS} = 320\text{ V}$<br>$V_{GS} = 0\text{ V}$ , $V_{DS} = 400\text{ V}$   | 2N7224U<br>2N7225U<br>2N7227U<br>2N7228U<br>$I_{DSS1}$    |                          | 25                               | $\mu\text{A}$ |
| Drain Current<br>$V_{GS} = 0\text{ V}$ , $V_{DS} = 80\text{ V}$ , $T_J = +125\text{ }^\circ\text{C}$<br>$V_{GS} = 0\text{ V}$ , $V_{DS} = 160\text{ V}$ , $T_J = +125\text{ }^\circ\text{C}$<br>$V_{GS} = 0\text{ V}$ , $V_{DS} = 320\text{ V}$ , $T_J = +125\text{ }^\circ\text{C}$<br>$V_{GS} = 0\text{ V}$ , $V_{DS} = 400\text{ V}$ , $T_J = +125\text{ }^\circ\text{C}$ | 2N7224U<br>2N7225U<br>2N7227U<br>2N7228U<br>$I_{DSS2}$    |                          | 0.25                             | mA            |
| Static Drain-Source On-State Resistance<br>$V_{GS} = 10\text{ V}$ , $I_D = 21.0\text{ A}$ pulsed<br>$V_{GS} = 10\text{ V}$ , $I_D = 17.0\text{ A}$ pulsed<br>$V_{GS} = 10\text{ V}$ , $I_D = 9.0\text{ A}$ pulsed<br>$V_{GS} = 10\text{ V}$ , $I_D = 8.0\text{ A}$ pulsed  | 2N7224U<br>2N7225U<br>2N7227U<br>2N7228U<br>$r_{DS(on)1}$ |                          | 0.070<br>0.100<br>0.315<br>0.415 | $\Omega$      |
| Static Drain-Source On-State Resistance<br>$V_{GS} = 10\text{ V}$ , $I_D = 34.0\text{ A}$ pulsed<br>$V_{GS} = 10\text{ V}$ , $I_D = 27.4\text{ A}$ pulsed<br>$V_{GS} = 10\text{ V}$ , $I_D = 14.0\text{ A}$ pulsed<br>$V_{GS} = 10\text{ V}$ , $I_D = 12.0\text{ A}$ pulsed  | 2N7224U<br>2N7225U<br>2N7227U<br>2N7228U<br>$r_{DS(on)2}$ |                          | 0.081<br>0.105<br>0.415<br>0.515 | $\Omega$      |
| Static Drain-Source On-State Resistance<br>$T_J = +125\text{ }^\circ\text{C}$<br>$V_{GS} = 10\text{ V}$ , $I_D = 21.0\text{ A}$ pulsed<br>$V_{GS} = 10\text{ V}$ , $I_D = 17.0\text{ A}$ pulsed<br>$V_{GS} = 10\text{ V}$ , $I_D = 9.0\text{ A}$ pulsed<br>$V_{GS} = 10\text{ V}$ , $I_D = 8.0\text{ A}$ pulsed  | 2N7224U<br>2N7225U<br>2N7227U<br>2N7228U<br>$r_{DS(on)3}$ |                          | 0.11<br>0.17<br>0.68<br>0.90     | $\Omega$      |
| Diode Forward Voltage<br>$V_{GS} = 0\text{ V}$ , $I_D = 34.0\text{ A}$ pulsed<br>$V_{GS} = 0\text{ V}$ , $I_D = 27.4\text{ A}$ pulsed<br>$V_{GS} = 0\text{ V}$ , $I_D = 14.0\text{ A}$ pulsed<br>$V_{GS} = 0\text{ V}$ , $I_D = 12.0\text{ A}$ pulsed  | 2N7224U<br>2N7225U<br>2N7227U<br>2N7228U<br>$V_{SD}$      |                          | 1.8<br>1.9<br>1.7<br>1.7         | V             |

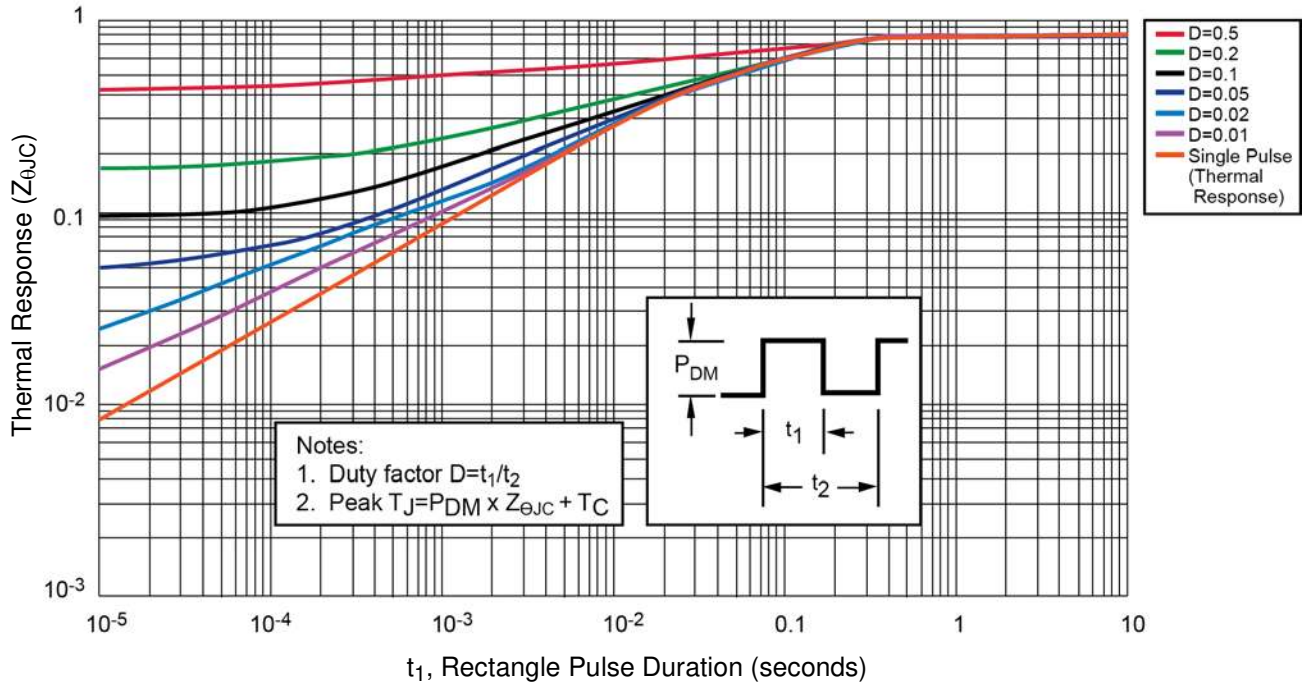
**ELECTRICAL CHARACTERISTICS @  $T_A = +25\text{ }^\circ\text{C}$ , unless otherwise noted (continued)**
**DYNAMIC CHARACTERISTICS**

| Parameters / Test Conditions  | Symbol      | Min. | Max. | Unit |
|---|-------------|------|------|------|
| <b>Gate Charge:</b>   |             |      |      |      |
| On-State Gate Charge  |             |      |      |      |
| $V_{GS} = 10\text{ V}$ , $I_D = 34.0\text{ A}$ , $V_{DS} = 50\text{ V}$ 2N7224U | $Q_{g(on)}$ |      | 125  | nC   |
| $V_{GS} = 10\text{ V}$ , $I_D = 27.4\text{ A}$ , $V_{DS} = 50\text{ V}$ 2N7225U |             | 115  |      |      |
| $V_{GS} = 10\text{ V}$ , $I_D = 14.0\text{ A}$ , $V_{DS} = 50\text{ V}$ 2N7227U |             | 110  |      |      |
| $V_{GS} = 10\text{ V}$ , $I_D = 12.0\text{ A}$ , $V_{DS} = 50\text{ V}$ 2N7228U |             | 120  |      |      |
| Gate to Source Charge   |             |      |      |      |
| $V_{GS} = 10\text{ V}$ , $I_D = 34.0\text{ A}$ , $V_{DS} = 50\text{ V}$ 2N7224U | $Q_{gs}$    |      | 22   | nC   |
| $V_{GS} = 10\text{ V}$ , $I_D = 27.4\text{ A}$ , $V_{DS} = 50\text{ V}$ 2N7225U |             | 22   |      |      |
| $V_{GS} = 10\text{ V}$ , $I_D = 14.0\text{ A}$ , $V_{DS} = 50\text{ V}$ 2N7227U |             | 18   |      |      |
| $V_{GS} = 10\text{ V}$ , $I_D = 12.0\text{ A}$ , $V_{DS} = 50\text{ V}$ 2N7228U |             | 19   |      |      |
| Gate to Drain Charge  |             |      |      |      |
| $V_{GS} = 10\text{ V}$ , $I_D = 34.0\text{ A}$ , $V_{DS} = 50\text{ V}$ 2N7224U | $Q_{gd}$    |      | 65   | nC   |
| $V_{GS} = 10\text{ V}$ , $I_D = 27.4\text{ A}$ , $V_{DS} = 50\text{ V}$ 2N7225U |             | 60   |      |      |
| $V_{GS} = 10\text{ V}$ , $I_D = 14.0\text{ A}$ , $V_{DS} = 50\text{ V}$ 2N7227U |             | 65   |      |      |
| $V_{GS} = 10\text{ V}$ , $I_D = 12.0\text{ A}$ , $V_{DS} = 50\text{ V}$ 2N7228U |             | 70   |      |      |

**SWITCHING CHARACTERISTICS**

| Parameters / Test Conditions  | Symbol       | Min. | Max. | Unit |
|---|--------------|------|------|------|
| Turn-on delay time  |              |      |      |      |
| $I_D = 34.0\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 50\text{ V}$ 2N7224U  | $t_{d(on)}$  |      | 35   | ns   |
| $I_D = 27.4\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 100\text{ V}$ 2N7225U |              |      |      |      |
| $I_D = 14.0\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 200\text{ V}$ 2N7227U |              |      |      |      |
| $I_D = 12.0\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 250\text{ V}$ 2N7228U |              |      |      |      |
| Rinse time  |              |      |      |      |
| $I_D = 34.0\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 50\text{ V}$ 2N7224U  | $t_r$        |      | 190  | ns   |
| $I_D = 27.4\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 100\text{ V}$ 2N7225U |              |      |      |      |
| $I_D = 14.0\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 200\text{ V}$ 2N7227U |              |      |      |      |
| $I_D = 12.0\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 250\text{ V}$ 2N7228U |              |      |      |      |
| Turn-off delay time   |              |      |      |      |
| $I_D = 34.0\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 50\text{ V}$ 2N7224U  | $t_{d(off)}$ |      | 170  | ns   |
| $I_D = 27.4\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 100\text{ V}$ 2N7225U |              |      |      |      |
| $I_D = 14.0\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 200\text{ V}$ 2N7227U |              |      |      |      |
| $I_D = 12.0\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 250\text{ V}$ 2N7228U |              |      |      |      |
| Fall time   |              |      |      |      |
| $I_D = 34.0\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 50\text{ V}$ 2N7224U  | $t_f$        |      | 130  | ns   |
| $I_D = 27.4\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 100\text{ V}$ 2N7225U |              |      |      |      |
| $I_D = 14.0\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 200\text{ V}$ 2N7227U |              |      |      |      |
| $I_D = 12.0\text{ A}$ , $V_{GS} = 10\text{ V}$ , $R_G = 2.35\text{ }\Omega$ , $V_{DD} = 250\text{ V}$ 2N7228U |              |      |      |      |
| Diode Reverse Recovery Time   |              |      |      |      |
| $di/dt \leq 100\text{ A}/\mu\text{s}$ , $V_{DD} \leq 30\text{ V}$ , $I_F = 34.0\text{ A}$ 2N7224U             | $t_{rr}$     |      | 500  | ns   |
| $di/dt \leq 100\text{ A}/\mu\text{s}$ , $V_{DD} \leq 30\text{ V}$ , $I_F = 27.4\text{ A}$ 2N7225U             |              | 950  |      |      |
| $di/dt \leq 100\text{ A}/\mu\text{s}$ , $V_{DD} \leq 30\text{ V}$ , $I_F = 14.0\text{ A}$ 2N7227U             |              | 1200 |      |      |
| $di/dt \leq 100\text{ A}/\mu\text{s}$ , $V_{DD} \leq 30\text{ V}$ , $I_F = 12.0\text{ A}$ 2N7228U             |              | 1600 |      |      |

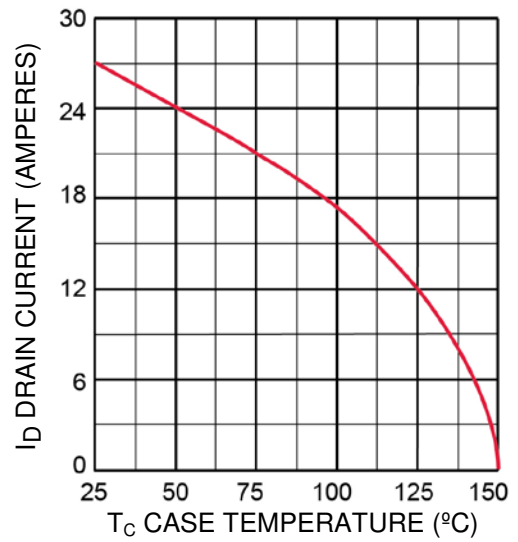
GRAPHS



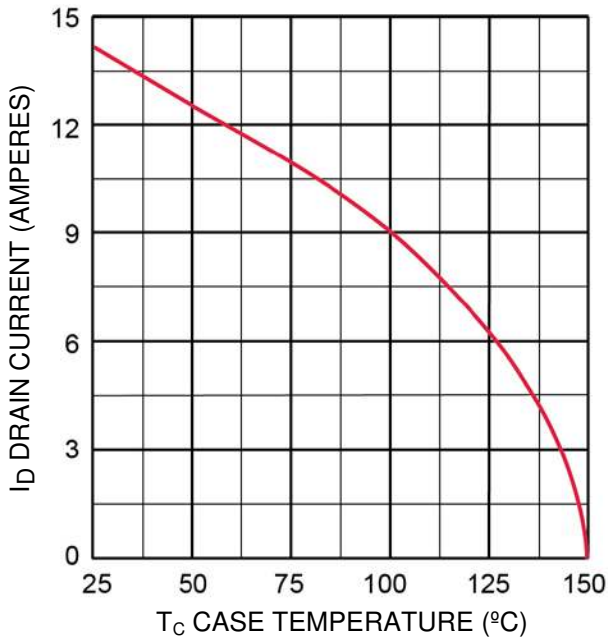
**FIGURE 1**  
Thermal Impedance Curves

**GRAPHS (continued)**
**FIGURE 2 – Maximum Drain Current vs Case Temperature Graphs**

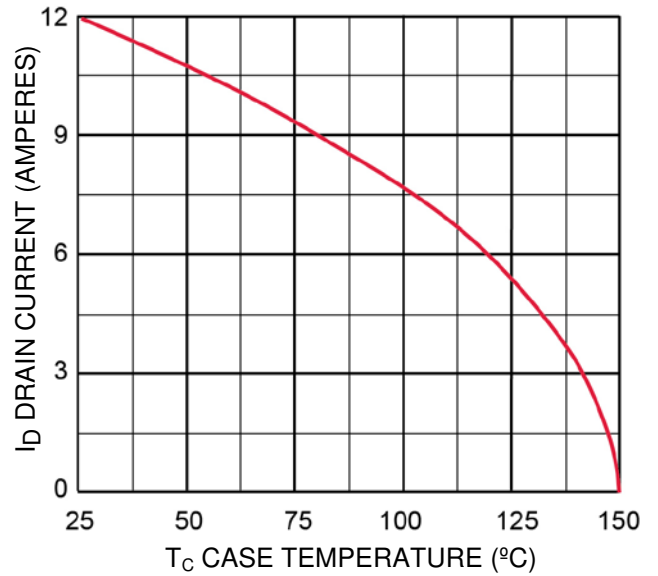

For 2N7224U



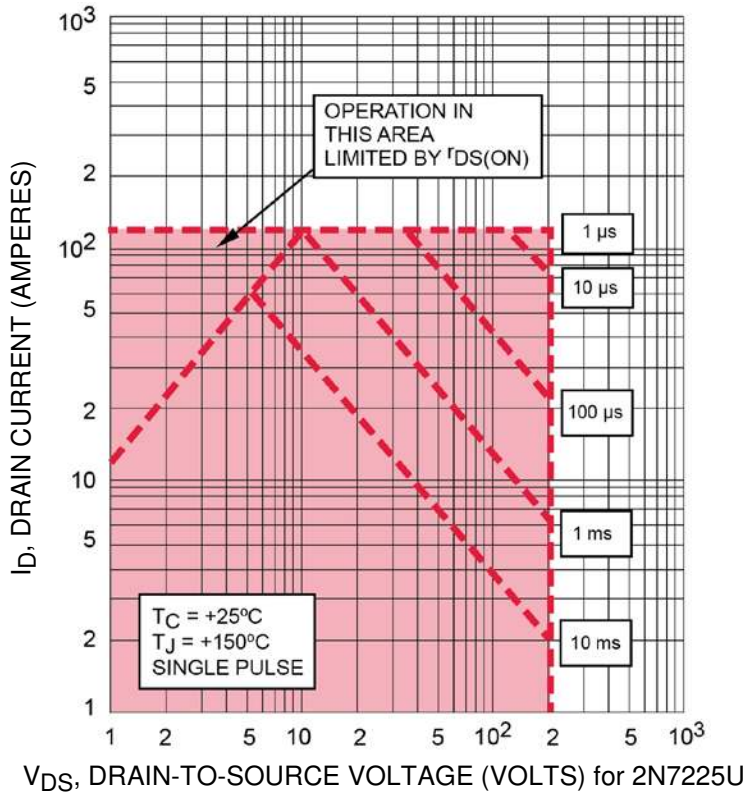
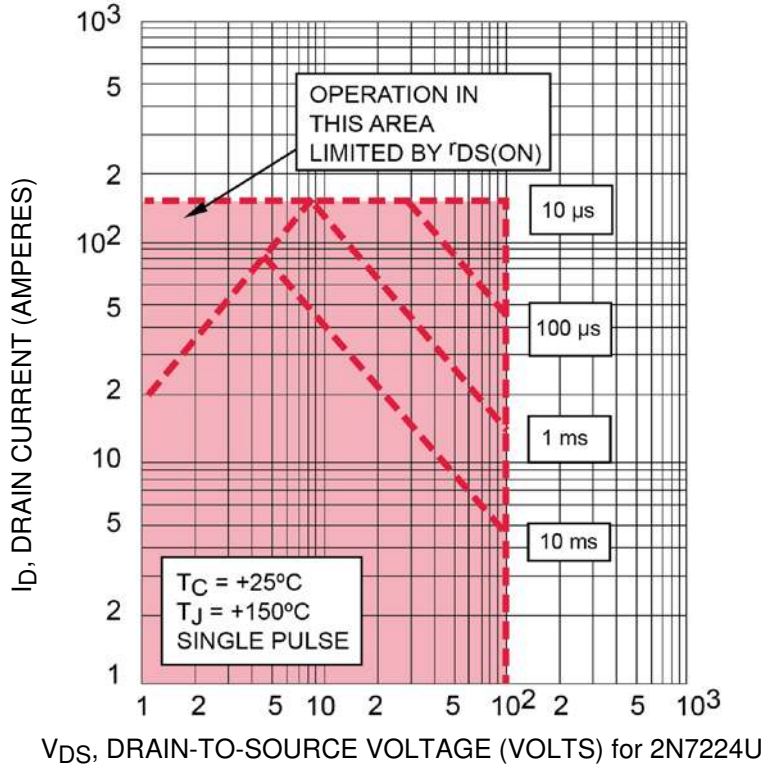
For 2N7225U

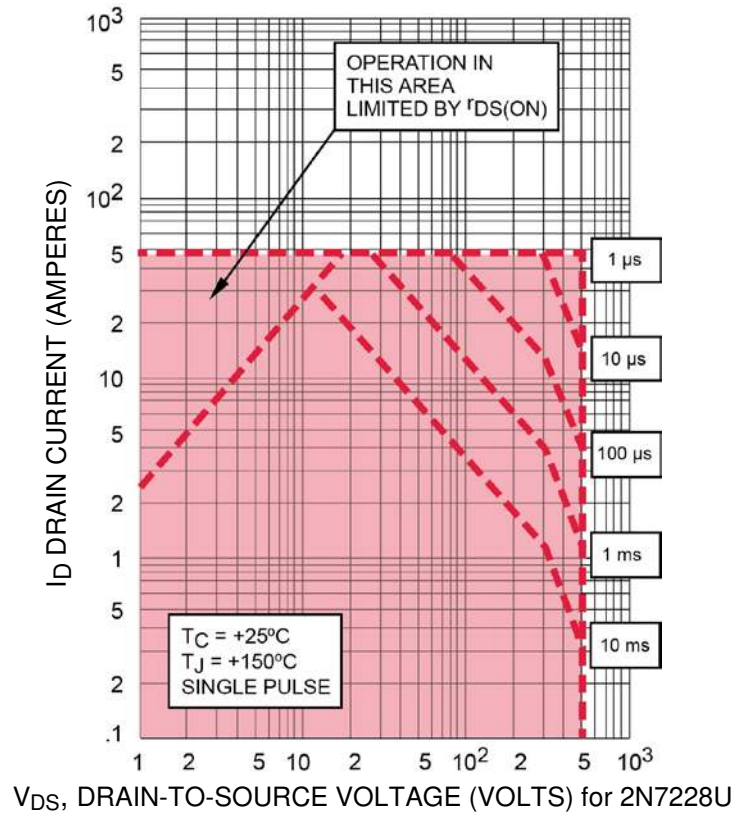
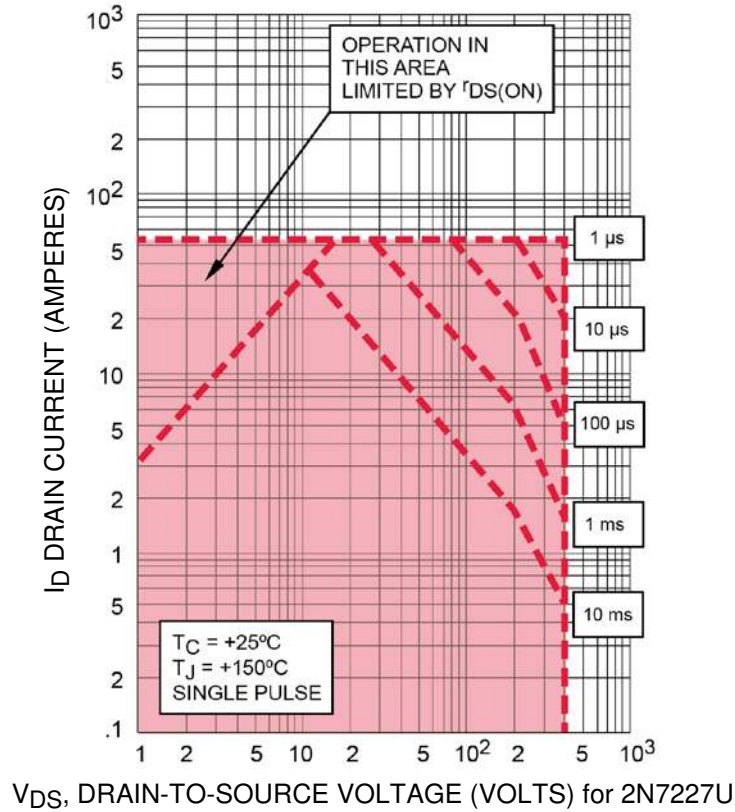


For 2N7227U

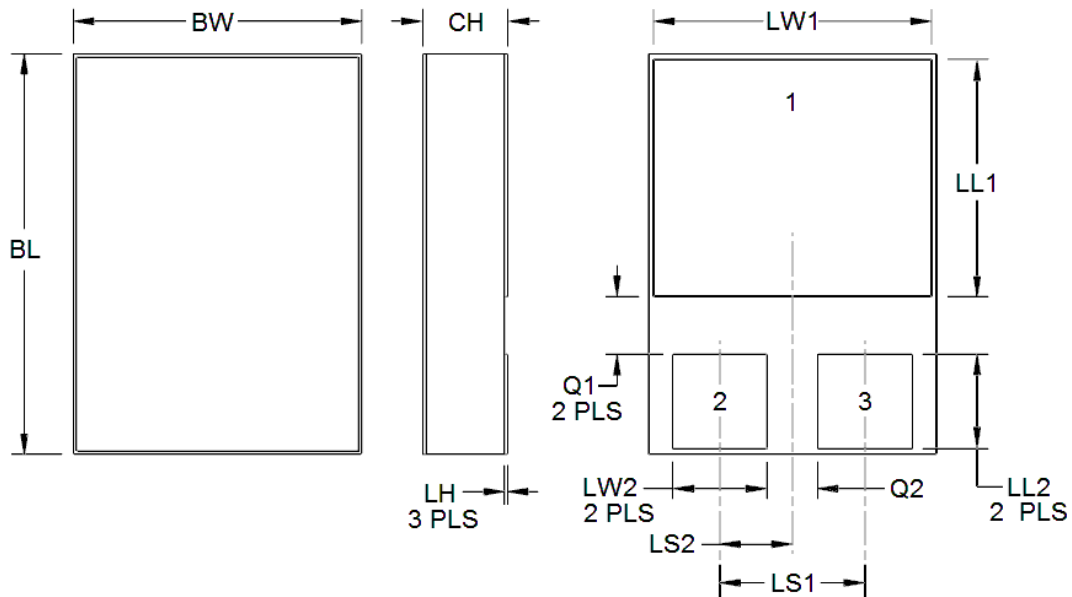


For 2N7228U

**GRAPHS (continued)**
**FIGURE 3 – Maximum Safe Operating Area**


**GRAPHS (continued)**




**PACKAGE DIMENSIONS**

**NOTES:**

1. Dimensions are in inches.
2. Millimeters are given for general information only.
3. The lid shall be electrically isolated from the drain, gate and source.
4. In accordance with ASME Y14.5M, diameters are equivalent to  $\Phi$ x symbology.

| Symbol        | DIMENSIONS |      |             |       |
|---------------|------------|------|-------------|-------|
|               | INCH       |      | MILLIMETERS |       |
|               | Min        | Max  | Min         | Max   |
| <b>BL</b>     | .620       | .630 | 15.75       | 16.00 |
| <b>BW</b>     | .445       | .455 | 11.30       | 11.56 |
| <b>CH</b>     | -          | .142 | -           | 3.60  |
| <b>LH</b>     | .010       | .020 | .026        | .050  |
| <b>LL1</b>    | .410       | .420 | 10.41       | 10.67 |
| <b>LL2</b>    | .152       | .162 | 3.86        | 4.11  |
| <b>LS1</b>    | .210 BSC   |      | 5.33 BSC    |       |
| <b>LS2</b>    | .105 BSC   |      | 2.67 BSC    |       |
| <b>LW1</b>    | .370       | .380 | 9.40        | 9.65  |
| <b>LW2</b>    | .135       | .145 | 3.43        | 3.68  |
| <b>Q1</b>     | .030       | -    | 0.76        | -     |
| <b>Q2</b>     | .035       | -    | 0.89        | -     |
| <b>Term 1</b> | Drain      |      |             |       |
| <b>Term 2</b> | Gate       |      |             |       |
| <b>Term 3</b> | Source     |      |             |       |